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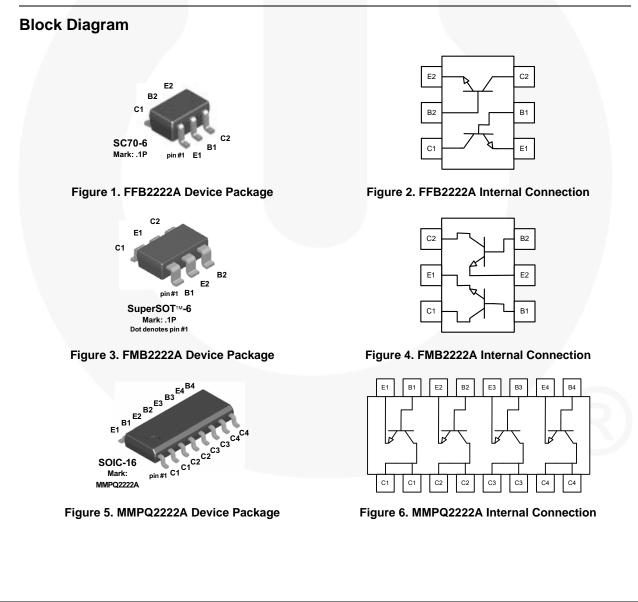
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FFB2222A / FMB2222A / MMPQ2222A NPN Multi-Chip General-Purpose Amplifier

Description

This device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA. Sourced from process 19.



FFB2222A / FMB2222A / MMPQ2222A — NPN Multi-Chip General-Purpose Amplifier

October 2015

Ordering Information

Part Number	Top Mark	Package	Packing Method
FFB2222A	.1P	SC70 6L	Tape and Reel
FMB2222A	.1P	SSOT 6L	Tape and Reel
MMPQ2222A	MMPQ2222A	SOIC 16L	Tape and Reel

Absolute Maximum Ratings⁽¹⁾

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	45	V
V _{CBO}	Collector-Base Voltage	75	V
V _{EBO}	Emitter-Base Voltage	5.0	V
۱ _C	Collector Current - Continuous	500	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 to +150	°C

Note:

1. These ratings are based on a maximum junction temperature of 150°C. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics⁽²⁾

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Max.			Unit
		FFB2222A	FMB2222A	MMPQ2222A	Unit
P _D	Total Device Dissipation	300	700	1,000	mW
	Derate Above 25°C	2.4	5.6	8.0	mW/°C
R _{θJA}	Thermal Resistance, Junction-to-Ambient	415	180		
	Thermal Resistance, Junction-to-Ambient, Effective 4 Dies			125	°C/W
	Thermal Resistance, Junction-to-Ambient, Each Die			240	

Note:

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

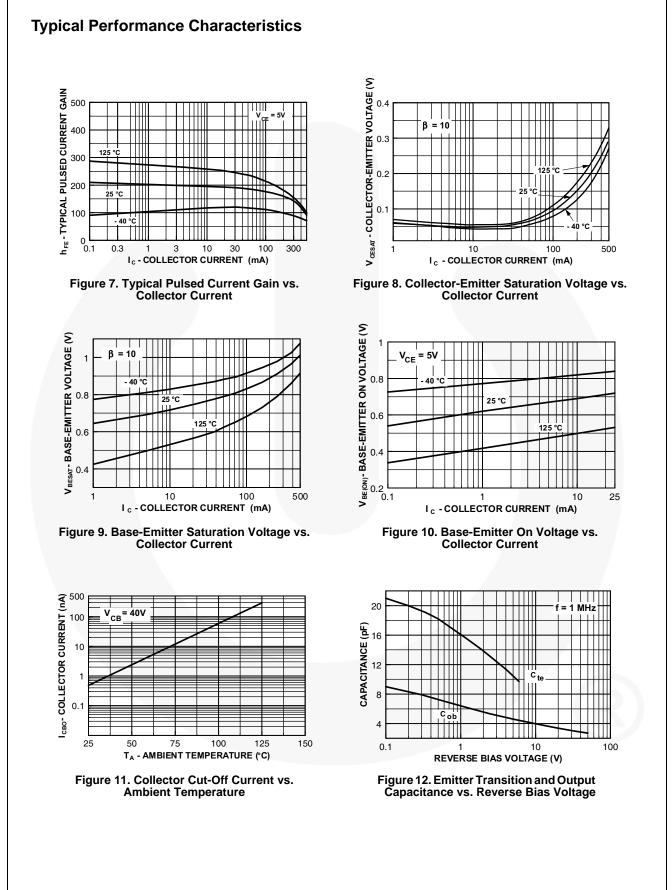
Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage ⁽³⁾	I _C = 10 mA, I _B = 0	40			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	I _C = 10 μA, I _E = 0	75			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	5.0			V
I _{CBO}	Collector Cut-Off Current	V _{CB} = 60 V, I _E = 0			10	nA
I _{EBO}	Emitter Cut-Off Current	V _{EB} = 3.0 V, I _C = 0			10	nA
h _{FE}	DC Current Gain	I _C = 0.1 mA, V _{CE} = 10 V	35			
		I _C = 1.0 mA, V _{CE} = 10 V	50			
		I _C = 10 mA, V _{CE} = 10 V	75			
		I _C = 150 mA, V _{CE} = 10 V ⁽³⁾	100		300	
		$I_{\rm C}$ = 150 mA, $V_{\rm CE}$ = 1.0 V ⁽³⁾	50			
		I _C = 500 mA, V _{CE} = 10 V ⁽³⁾	40			
V _{CE} (sat)	Collector-Emitter Saturation Voltage ⁽³⁾	I _C = 150 mA, I _B = 15 mA			0.3	v
		I _C = 500 mA, I _B = 50 mA			1.0	
V _{BE} (sat)	Base-Emitter Saturation Voltage ⁽³⁾	I _C = 150 mA, I _B = 15 mA			1.2	- v
		I _C = 500 mA, I _B = 50 mA			2.0	
f _T	Current Gain - Bandwidth Product	I _C = 20 mA, V _{CE} = 20 V, f = 100 MHz		300		MHz
C _{obo}	Output Capacitance	V _{CB} = 10 V, I _E = 0, f = 100 kHz		4.0		pF
C _{ibo}	Input Capacitance	V _{EB} = 0.5 V, I _C = 0, f = 100 kHz		20		pF
NF	Noise Figure	I_{C} = 100 μA, V _{CE} = 10 V, R _S = 1.0 kΩ, f = 1.0 kHz		2.0		dB
t _d	Delay Time	$V_{CC} = 30 \text{ V}, V_{BE(OFF)} = 0.5 \text{ V},$ $I_{C} = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$		8		ns
t _r	Rise Time			20		ns
t _s	Storage Time	$V_{CC} = 30 \text{ V}, \text{ I}_{C} = 150 \text{ mA},$ $\text{I}_{B1} = \text{I}_{B2} = 15 \text{ mA}$		180		ns
t _f	Fall Time			40		ns

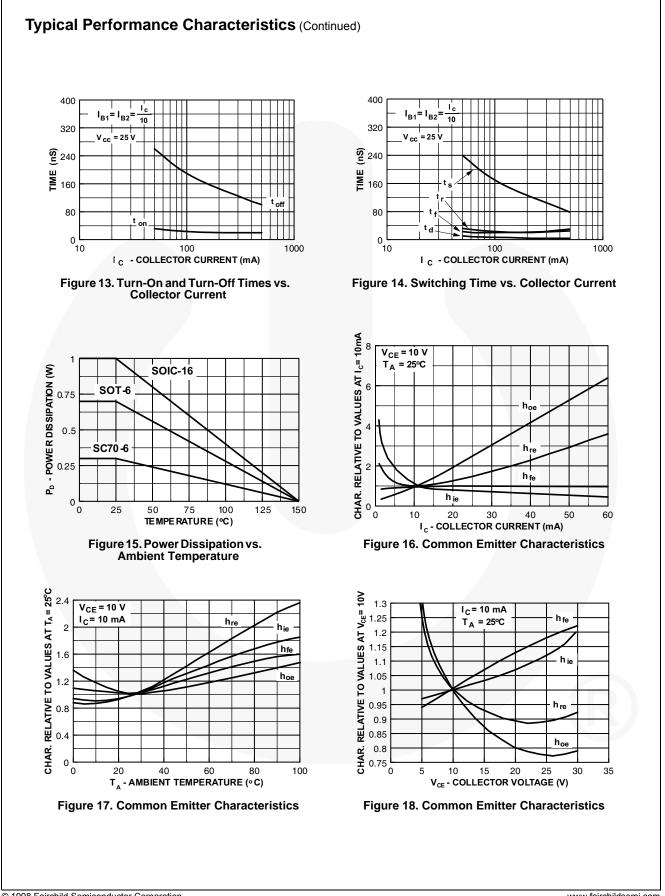
Note:

3. Pulse test: pulse width \leq 300 µs, duty cycle \leq 2.0%.

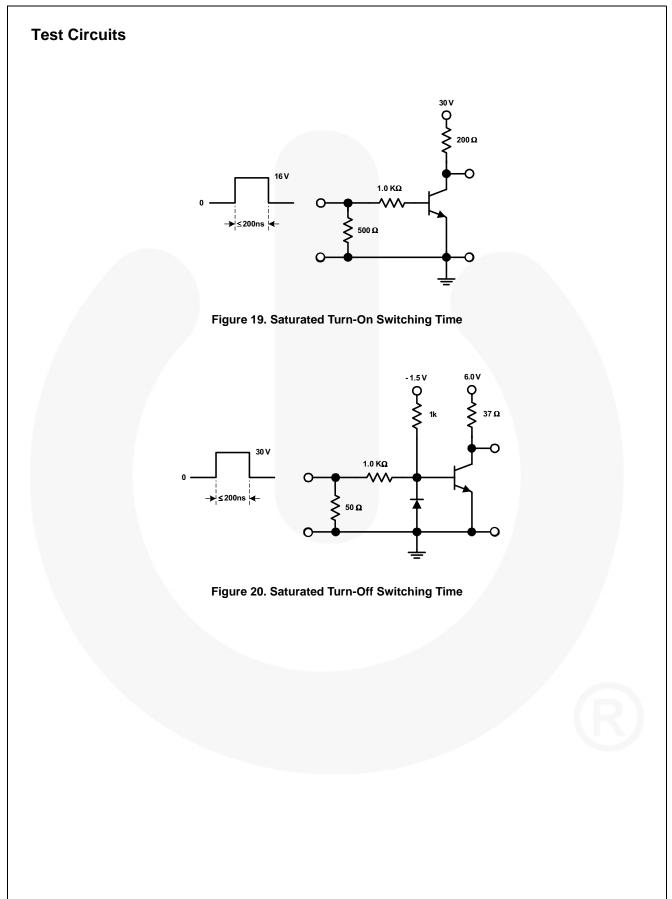


FFB2222A / FMB2222A / MMPQ2222A —

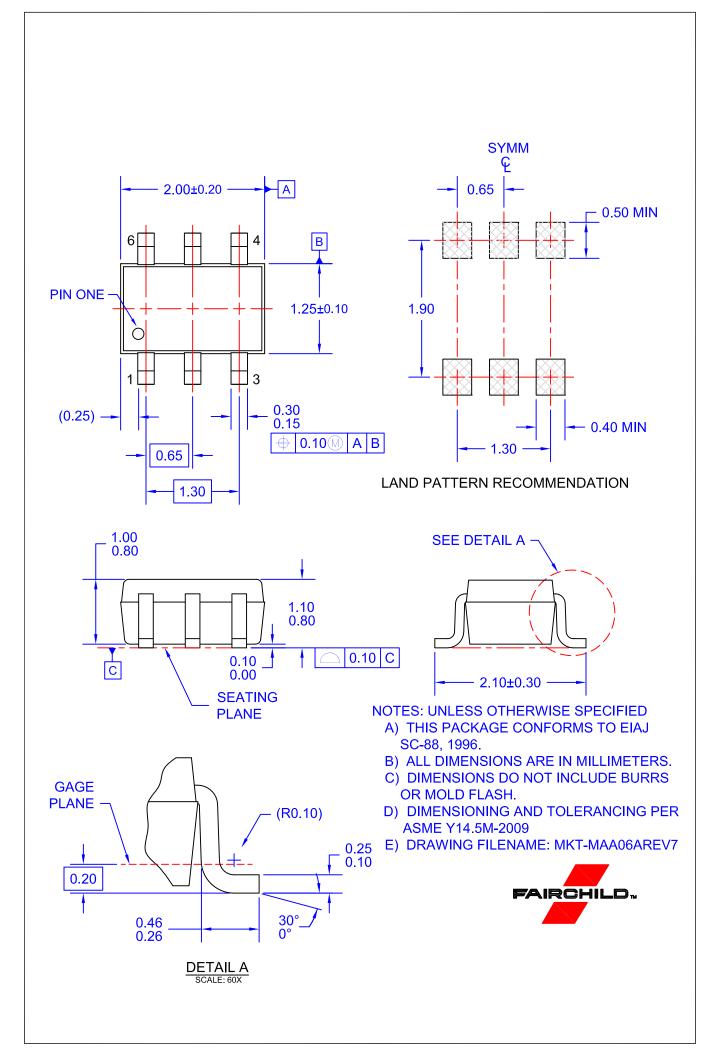
NPN Multi-Chip General-Purpose Amplifier

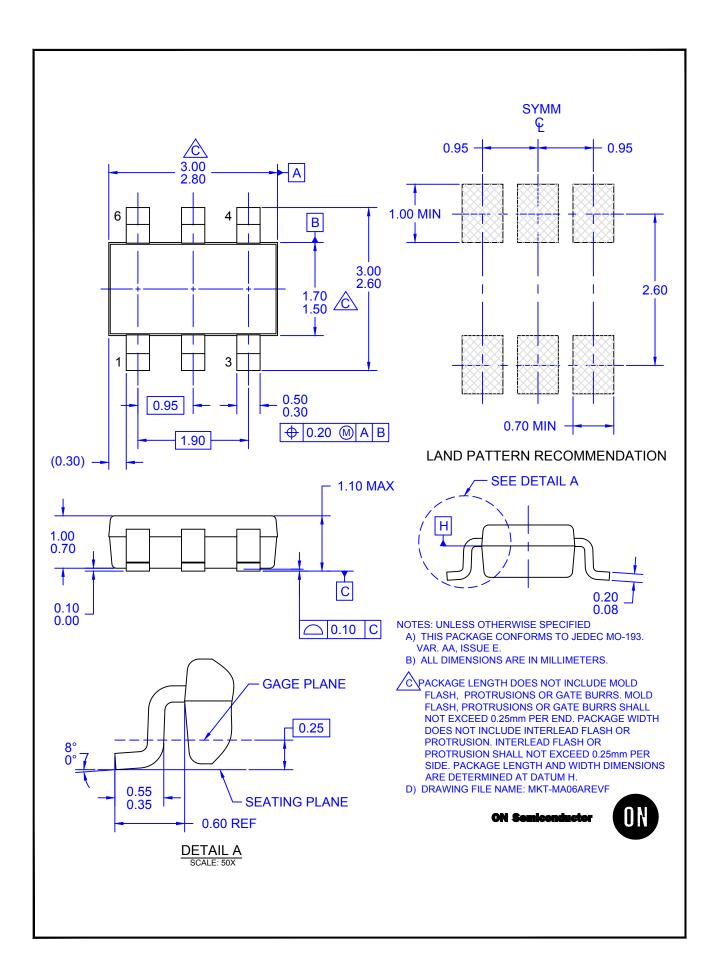


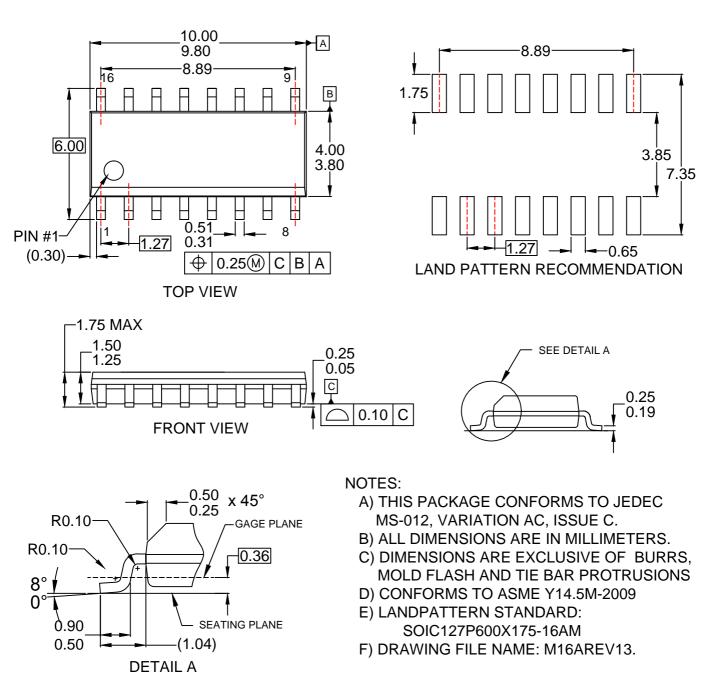
© 1998 Fairchild Semiconductor Corporation FFB2222A / FMB2222A / MMPQ2222A Rev. 1.4 FFB2222A / FMB2222A / MMPQ2222A — NPN Multi-Chip General-Purpose Amplifier



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